

PC924

OPIC Photocoupler for IGBT Drive of Inverter

* Lead forming type (I type) and taping reel type (P type) are also available. (PC924I/PC924P) (Page 656)

■ Features

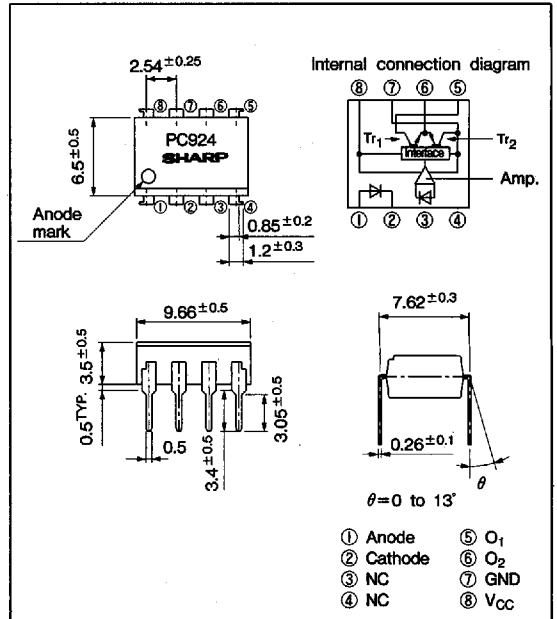
1. Built-in direct drive circuit for IGBT drive (I_{O1P} , I_{O2P} : 0.4A)
2. High speed response (t_{PLH} , t_{PHL} : MAX. 2.0 μ s)
3. Wide operating supply voltage range (V_{CC} : 15 to 30V at $T_a = -10$ to 60°C)
4. High noise resistance type
 CM_H : MIN. -1500V/ μ s
 CM_L : MIN. 1500V/ μ s
5. High isolation voltage (V_{iso} : 5 000V_{rms})

■ Applications

1. IGBT drive for inverter control

■ Outline Dimensions

(Unit : mm)



* "OPIC" (Optical IC) is a trademark of the SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

■ Absolute Maximum Ratings

(Unless specified, $T_a = T_{opr}$)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	25	mA
	Reverse voltage	V_R	6	V
Output	Supply voltage	V_{CC}	35	V
	O_1 output current	I_{O1}	0.1	A
	* O_1 peak output current	I_{O1P}	0.4	A
	O_2 output current	I_{O2}	0.1	A
	* O_2 peak output current	I_{O2P}	0.4	A
	O_1 output voltage	V_{O1}	35	V
	Power dissipation	P_O	500	mW
	Total power dissipation	P_{tot}	550	mW
	*2 Isolation voltage	V_{iso}	5 000	V _{rms}
	Operating temperature	T_{opr}	-25 to +80	°C
	Storage temperature	T_{stg}	-55 to +125	°C
	*3 Soldering temperature	T_{sol}	260	°C

- *1 Pulse width $\leq 0.15 \mu$ s, Duty ratio 0.01
 *2 40 to 60%RH, AC for 1 minute, $T_a = 25^\circ\text{C}$
 *3 For 10 seconds

8180798 0011844 795

■ Electro-optical Characteristics

($T_a = T_{opr}$ unless otherwise specified)

Parameter		Symbol	*Conditions	MIN.	TYP.	MAX.	Unit	Fig.	
Input	Forward voltage	V_{F1}	$T_a = 25^\circ\text{C}$, $I_F = 20\text{mA}$	—	1.2	1.4	V	—	
		V_{F2}	$T_a = 25^\circ\text{C}$, $I_F = 0.2\text{mA}$	0.6	0.9	—	V	—	
	Reverse current	I_R	$T_a = 25^\circ\text{C}$, $V_R = 4\text{V}$	—	—	10	μA	—	
	Terminal capacitance	C_t	$T_a = 25^\circ\text{C}$, $V = 0$, $f = 1\text{kHz}$	—	30	250	pF	—	
Output	Operating supply voltage	V_{CC}	$T_a = -10$ to 60°C	15	—	30	V	—	
				15	—	24	V		
	O_1 low level output voltage	V_{O1L}	$V_{CC1} = 12\text{V}$, $V_{CC2} = -12\text{V}$ $I_{O1} = 0.1\text{A}$, $I_F = 10\text{mA}$	—	0.2	0.4	V	1	
	O_2 high level output voltage	V_{O2H}	$V_{CC} = V_{O1} = 24\text{V}$, $I_{O2} = -0.1\text{A}$, $I_F = 10\text{mA}$	18	21	—	V	2	
	O_2 low level output voltage	V_{O2L}	$V_{CC} = 24\text{V}$, $I_{O2} = 0.1\text{A}$, $I_F = 0$	—	1.2	2.0	V	3	
	O_1 leak current	I_{O1L}	$T_a = 25^\circ\text{C}$, $V_{CC} = V_{O1} = 35\text{V}$, $I_F = 0$	—	—	500	μA	4	
	O_2 leak current	I_{O2L}	$T_a = 25^\circ\text{C}$, $V_{CC} = V_{O2} = 35\text{V}$, $I_F = 10\text{mA}$	—	—	500	μA	5	
	High level supply current	I_{CCH}	$T_a = 25^\circ\text{C}$, $V_{CC} = 24\text{V}$, $I_F = 10\text{mA}$	—	6	10	mA	6	
$V_{CC} = 24\text{V}$, $I_F = 10\text{mA}$			—	—	14	mA			
Low level supply current	I_{CCL}	$T_a = 25^\circ\text{C}$, $V_{CC} = 24\text{V}$, $I_F = 0$	—	8	13	mA	6		
		$V_{CC} = 24\text{V}$, $I_F = 0$	—	—	17	mA			
Transfer characteristics	*5 "Low→High" threshold input current	I_{FLH}	$T_a = 25^\circ\text{C}$, $V_{CC} = 24\text{V}$	1.0	4.0	7.0	mA	7	
			$V_{CC} = 24\text{V}$	0.6	—	10.0	mA		
	Isolation resistance	R_{ISO}	$T_a = 25^\circ\text{C}$, DC=500V, 40 to 60%RH	5×10^{10}	10^{11}	—	Ω	—	
	Response time	"Low→High" propagation delay time	t_{PLH}	$T_a = 25^\circ\text{C}$, $V_{CC} = 24\text{V}$, $I_F = 10\text{mA}$ $R_C = 47\Omega$, $C_G = 3,000\text{pF}$	—	1.0	2.0	μs	8
		"High→Low" propagation delay time	t_{PHL}		—	1.0	2.0	μs	
		Rise time	t_r		—	0.2	0.5	μs	
		Fall time	t_f		—	0.2	0.5	μs	
Instantaneous common mode rejection voltage "Output : High level"	CM_H	$T_a = 25^\circ\text{C}$, $V_{CM} = 600\text{V(peak)}$ $I_F = 10\text{mA}$, $V_{CC} = 24\text{V}$, $\Delta V_{O2H} = 2.0\text{V}$	—1 500	—	—	V/ μs	9		
Instantaneous common mode rejection voltage "Output : Low level"	CM_L	$T_a = 25^\circ\text{C}$, $V_{CM} = 600\text{V(peak)}$ $I_F = 0$, $V_{CC} = 24\text{V}$, $\Delta V_{O2L} = 2.0\text{V}$	1 500	—	—	V/ μs			

*4 When measuring output and transfer characteristics, connect a by-pass capacitor (0.01 μF or more) between V_{CC} and GND near the device.

*5 I_{FLH} represents forward current when output goes from "Low" to "High".

■ Truth Table

Input	O_2 Output	Tr. 1	Tr. 2
ON	High level	ON	OFF
OFF	Low level	OFF	ON

6

Photocouplers

■ Test Circuit

Fig. 1

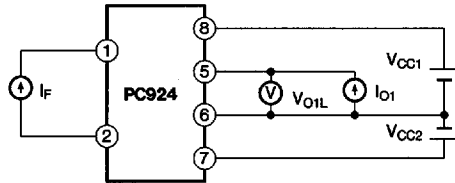


Fig. 3

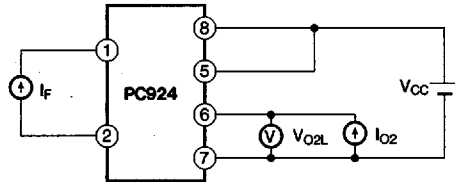


Fig. 5

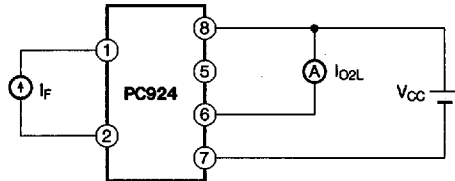


Fig. 7

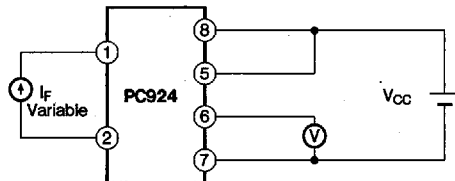


Fig. 9

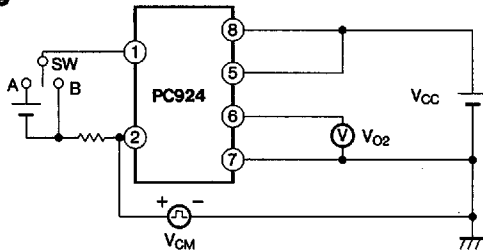


Fig. 2

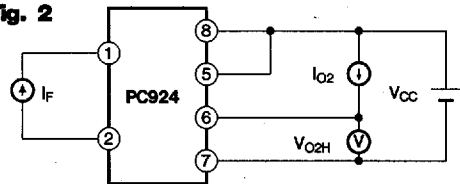


Fig. 4

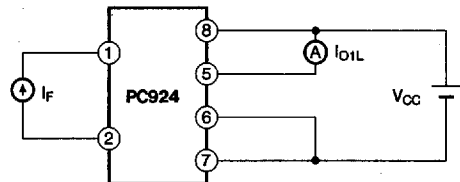


Fig. 6

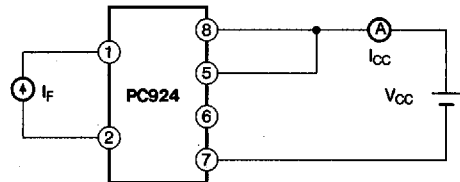


Fig. 8

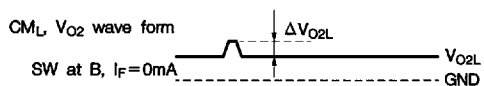
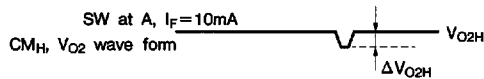
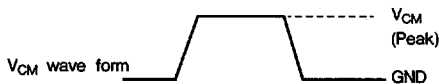
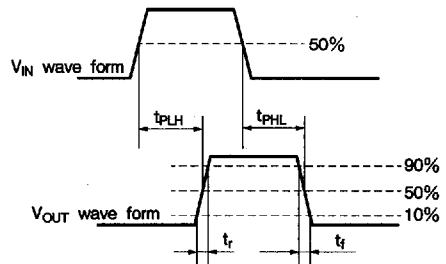
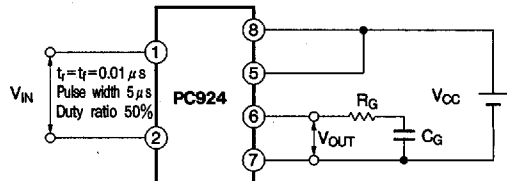


Fig.10 Forward Current vs. Ambient Temperature

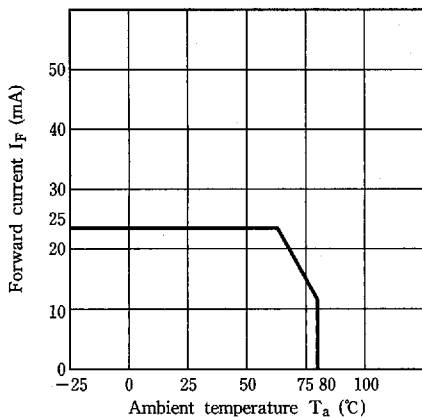


Fig.11 Power Dissipation vs. Ambient Temperature

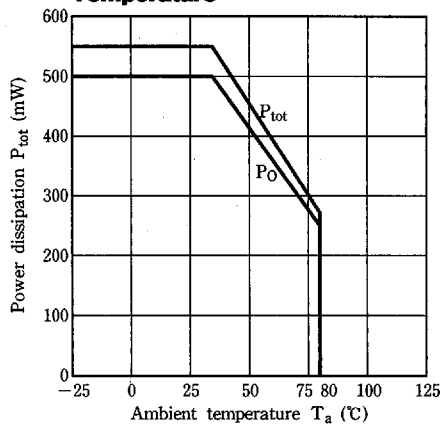


Fig.12 Forward Current vs. Forward Voltage

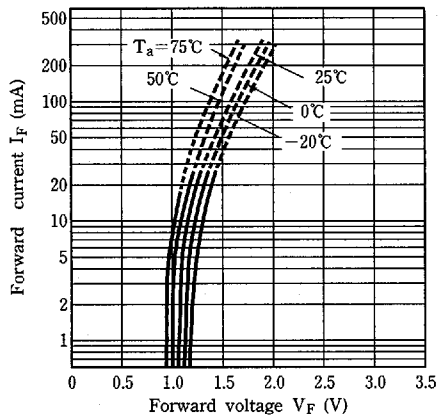


Fig.13 Relative Threshold Input Current vs. Supply Voltage

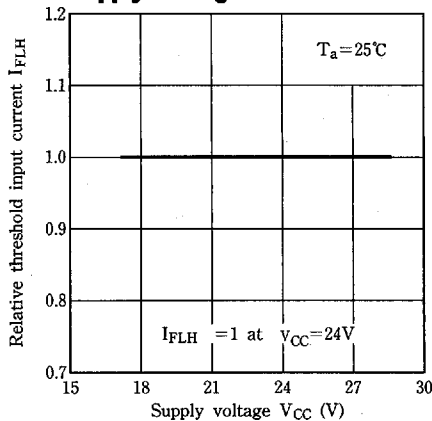


Fig.14 Relative Threshold Input Current vs. Ambient Temperature

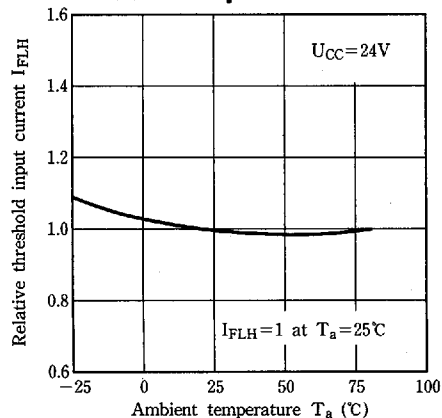


Fig.15 O_1 Low Level Output Voltage vs. O_1 Output Current

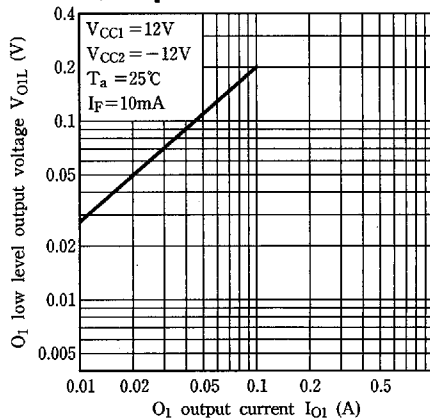


Fig.16 O₁ Low Level Output Voltage vs. Ambient Temperature

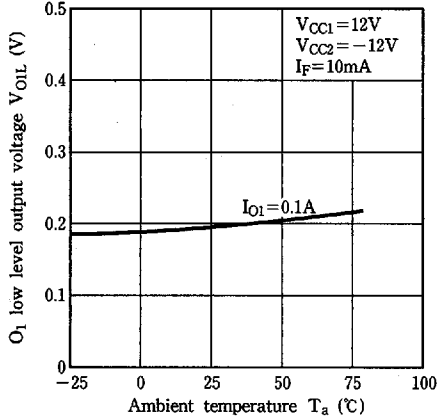


Fig.17 O₂ High Level Output Voltage vs. Supply Voltage

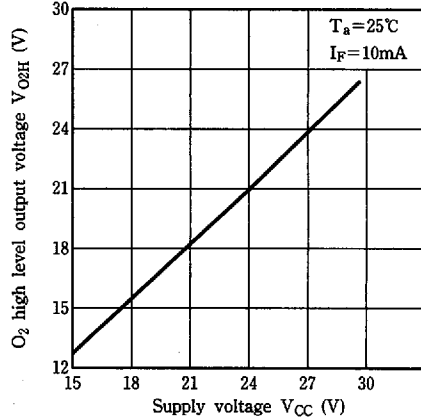


Fig.18 O₂ High Level Output Voltage vs. Ambient Temperature

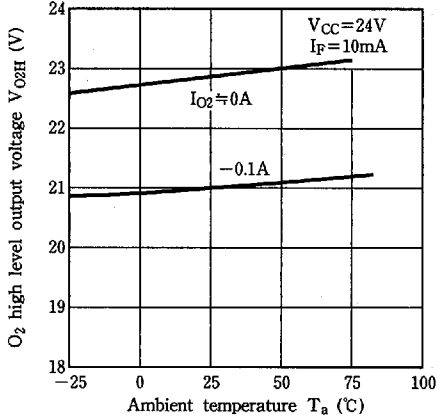


Fig.19 O₂ Low Level Output Voltage vs. O₂ Output Current

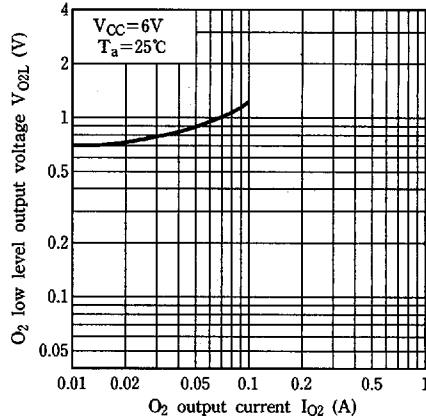


Fig.20 O₂ Low Level Output Voltage vs. Ambient Temperature

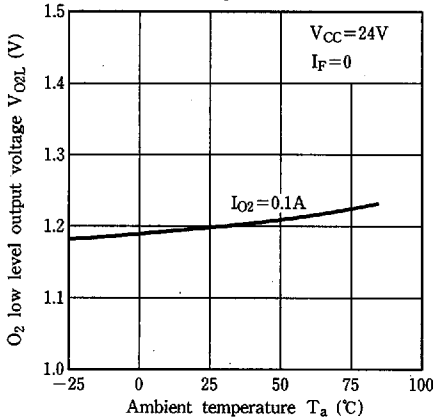


Fig.21 High Level Supply Current vs. Supply Voltage

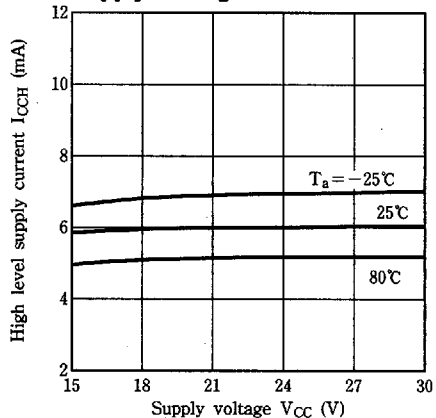


Fig.22 Low Level Supply Current vs. Supply Voltage

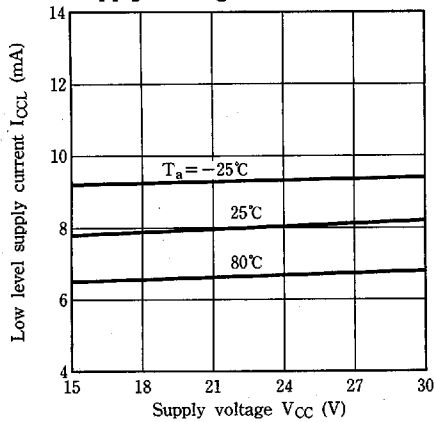


Fig.23 Propagation Delay Time vs. Forward Current

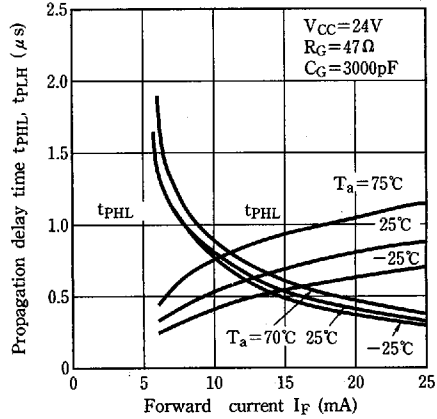
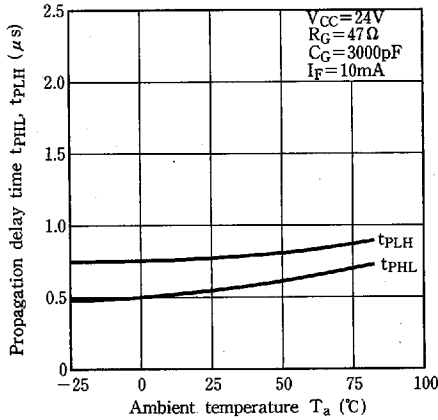
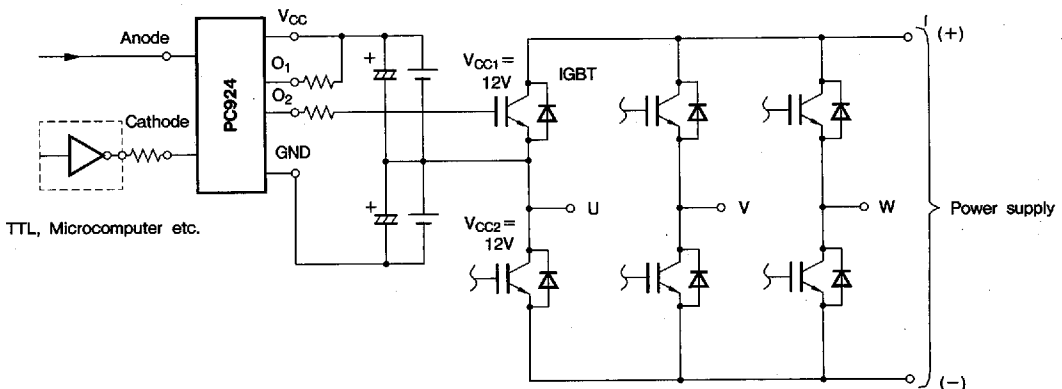


Fig.24 Propagation Delay Time vs. Ambient Temperature



Application Circuit (IGBT Drive for Inverter)



● Please refer to the chapter "Precautions for Use" (Page 78 to 93).